

### Low Noise Silicon Bipolar RF Transistor

- For low noise, low distortion broadband amplifiers in antenna and telecommunications systems up to 1.5 GHz at collector currents from 20 mA to 80 mA
- Power amplifier for DECT and PCN systems
- $f_T$  = 7.5 GHz,  $NF_{min}$  = 1.3 dB at 900 MHz
- Pb-free (RoHS compliant) and halogen-free package with visible leads
- Qualification report according to AEC-Q101 available





# ESD (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Marking	Pin Configuration					Package	
BFP196W	RIs	1 = E	2 = C	3 = E	4 = B	-	-	SOT343

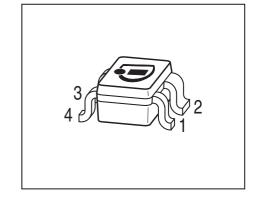
## **Maximum Ratings** at $T_A$ = 25 °C, unless otherwise specified

Parameter	Symbol	Value	Unit	
Collector-emitter voltage	$V_{CEO}$	12	V	
Collector-emitter voltage	V <sub>CES</sub>	20		
Collector-base voltage	$V_{\mathrm{CBO}}$	20		
Emitter-base voltage	$V_{EBO}$	2		
Collector current	I <sub>C</sub>	150	mA	
Base current	l <sub>B</sub>	15		
Total power dissipation <sup>1)</sup>	P <sub>tot</sub>	700	mW	
<i>T</i> <sub>S</sub> ≤ 69°C				
Junction temperature	TJ	150	°C	
Ambient temperature	T <sub>A</sub>	-65 150		
Storage temperature	T <sub>Stq</sub>	-65 150		

#### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>2)</sup>	R <sub>thJS</sub>	115	K/W

 $<sup>^1</sup>T_{
m S}$  is measured on the collector lead at the soldering point to the pcb



 $<sup>^2</sup>$ For the definition of  $R_{th,JS}$  please refer to Application Note AN077 (Thermal Resistance Calculation)



**Electrical Characteristics** at  $T_A$  = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics				•	•
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	12	-	_	V
$I_{\rm C}$ = 1 mA, $I_{\rm B}$ = 0	, ,				
Collector-emitter cutoff current	I <sub>CES</sub>	-	-	100	μΑ
$V_{CE} = 20 \text{ V}, V_{BE} = 0$					
Collector-base cutoff current	I <sub>CBO</sub>	-	-	100	nA
$V_{\rm CB} = 10 \text{ V}, I_{\rm E} = 0$					
Emitter-base cutoff current	I <sub>EBO</sub>	-	-	1	μΑ
$V_{\text{EB}} = 1 \text{ V}, I_{\text{C}} = 0$					
DC current gain	h <sub>FE</sub>	70	100	140	-
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 8 V, pulse measured					

2



**Electrical Characteristics** at  $T_A$  = 25 °C, unless otherwise specified

Parameter Parameter Stics at $I_A = 25$ °C, unless	Symbol	Peciliec	Unit			
		min.	Values typ.	max.		
AC Characteristics (verified by random sampling)						
Transition frequency	f <sub>T</sub>	5	7.5	-	GHz	
$I_{\rm C}$ = 70 mA, $V_{\rm CE}$ = 8 V, $f$ = 500 MHz						
Collector-base capacitance	C <sub>cb</sub>	-	0.86	1.3	pF	
$V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$ ,						
emitter grounded						
Collector emitter capacitance	C <sub>ce</sub>	-	0.4	-		
$V_{CE} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$ ,						
base grounded						
Emitter-base capacitance	C <sub>eb</sub>	-	3.9	-		
$V_{\text{EB}} = 0.5 \text{ V}, f = 1 \text{ MHz}, V_{\text{CB}} = 0$ ,						
collector grounded						
Minimum noise figure	NF <sub>min</sub>				dB	
$I_{\rm C}$ = 20 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,						
f = 900 MHz		-	1.3	-		
f = 1.8 GHz		-	2.3	-		
Power gain, maximum available <sup>1)</sup>	G <sub>ma</sub>				]	
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ , $Z_{\rm L}$ = $Z_{\rm Lopt}$ ,						
f = 900 MHz		-	19	-		
f = 1.8 GHz		-	12.5	-		
Transducer gain	S <sub>21e</sub>   <sup>2</sup>				dB	
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,						
f = 900 MHz		-	13	_		
f = 1.8 GHz		-	7	-		
Third order intercept point at output <sup>2)</sup>	IP <sub>3</sub>	-	32	-	dBm	
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,						
f = 0.9 GHz						
1dB Compression point at output	P <sub>-1dB</sub>	-	19	-	1	
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,						
f = 0.9 GHz						

 $<sup>^{1}</sup>G_{\text{ma}} = |S_{21} / S_{12}| (k - (k^{2} - 1)^{1/2})$ 

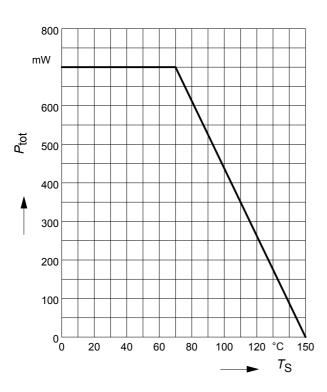
<sup>&</sup>lt;sup>2</sup>IP3 value depends on termination of all intermodulation frequency components.

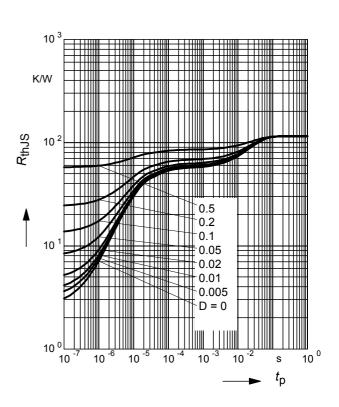
Termination used for this measurement is  $50\Omega$  from 0.2 MHz to 12 GHz



# Total power dissipation $P_{\text{tot}} = f(T_{\text{S}})$

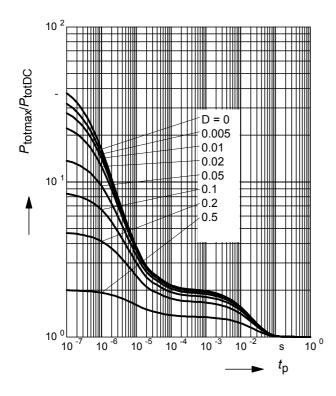
# Permissible Pulse Load $R_{thJS} = f(t_p)$





## **Permissible Pulse Load**

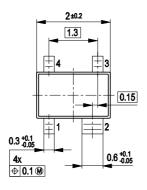
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_{p})$$

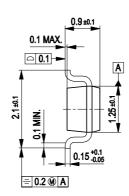




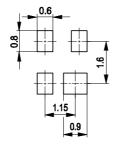
## Package Outline



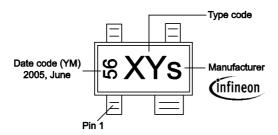




## **Foot Print**

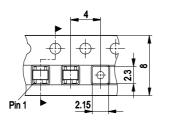


# Marking Layout (Example)



## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel







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